

EPO-TEK® H20E-LC Technical Data Sheet

For Reference Only

Electrically Conductive, Silver Epoxy

Date:	November 2019		Recommended Cure: 150°C / 1 Hour
Rev:	VII		
No. of Components:	Two		Minimum Alternative Cure(s):
Mix Ratio by Weight:	1:1		May not achieve performance properties listed below
Specific Gravity:	Part A: 2.42	Part B: 3.07	175°C / 45 Seconds
Pot Life:	4 Days		150°C / 5 Minutes
Shelf Life- Bulk:	One year at room temperature		120°C / 15 Minutes
			80°C / 3 Hours

NOTES:

• Container(s) should be kept closed when not in use.

• Filled systems should be stirred thoroughly before mixing and prior to use.

• Performance properties (rheology, conductivity, others) of the product may vary from those stated on the data sheet when bi-pak/syringe packaging or post-processing of any kind is performed. Epoxy's warranties shall not apply to any products that have been reprocessed or repackaged from Epoxy's delivered status/container into any other containers of any kind, including but not limited to syringes, bi-paks, cartridges, pouches, tubes, capsules, films or other packages.

Product Description: EPO-TEK® H20E-LC is a two component, silver-filled epoxy system designed specifically for chip bonding in microelectronic and optoelectronic applications. It is also used extensively for thermal management applications due to its high thermal conductivity. It has proven itself to be extremely reliable over many years of service and is the conductive adhesive of choice for low chloride applications.

Typical Properties: Cure condition: 150°C / 1 Hour Different batches, conditions & applications yield differing results. Data below is not guaranteed. To be used as a guide only, not as a specification. * denotes test on lot acceptance basis

PHYSICAL PROPERTIES:					
* Color (before cure):	Part A: Si	lver Pa	Part B: Silver		
* Consistency:	Smooth p	aste			
* Viscosity (23°C) @ 100 rpm:	2,2	00 - 3,200	cPs		
Thixotropic Index:		4.6			
* Glass Transition Temp:		≥ 80	°C (Dynamic Cure: 20-200°C/ISO 25 Min; Ramp -10-200°C @20°C/Min)		
Coefficient of Thermal Expansion (CTE)	:				
Below T		44			
Above T	g:	174	x 10 ⁻⁶ in/in°C		
Shore D Hardness:		60			
Lap Shear @ 23°C:		1,672	•		
Die Shear @ 23°C:		≥ 5	5 / 1		
Degradation Temp:		451	°C		
Weight Loss:					
@ 200°C		0.42			
@ 250°C		1.03			
@ 300°C):	1.96			
Suggested Operating Temperature:		< 300			
Storage Modulus:		939,871	psi		
Ion Content:	CI:	11 ppm			
	NH4+:	259 ppm			
* Particle Size:		≤ 45	microns		
ELECTRICAL AND THERMAL PROPERTIES:					
Thermal Conductivity:		2.0	W/mK		
* Volume Resistivity @ 23°C:		≤ 0.0004	Ohm-cm		

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EPO-TEK® H20E-LC Advantages & Suggested Application Notes:

- Especially recommended for use in high speed epoxy chip bonding systems where very fast cures are desired.
- Suggested for JEDEC Level III and II for plastic IC packaging.
- Capable of resisting TC wire bonding temperatures in the range of 300°C to 400°C.
- Ease of use: apply by dispensing, screen printing, die-stamping, or by hand.
- Especially suited for high power devices and high current flow; high power LEDs.
- Opto-electronic packaging material: LED, LCDs, and fiber optic components.